

### SAM™ Data Sheet SAM-1150-32-1ps-x, $\lambda = 1150 \text{ nm}$

Laser wavelength	$\lambda = 1150 \text{ nm}$
High reflection band (R > 66%)	$\lambda = 1080 \dots 1200 \text{ nm}$
Absorbance	$A_0 = 32 \%$
Modulation depth	$\Delta R = 20 \%$
Non-saturable loss	$A_{ns} = 12 \%$
Saturation fluence	$\Phi_{sat} = 70 \mu\text{J}/\text{cm}^2$
Relaxation time constant	$\tau \sim 1 \text{ ps}$
Damage threshold	$600 \text{ MW}/\text{cm}^2$
Chip area	4 mm x 4 mm; other dimensions on request
Chip thickness	450 $\mu\text{m}$
Protection	the SAM is protected with a dielectric front layer

Mounting option **x** denotes the type of mounting as follows:

<b>x</b> = 0	unmounted
<b>x</b> = 12.7 g	glued on a copper heat sink with 12.7 mm $\varnothing$
<b>x</b> = 25.4 g	glued on a copper heat sink with with 25.4 mm $\varnothing$
<b>x</b> = 12.7 s	soldered on a copper heat sink with with 12.7 mm $\varnothing$
<b>x</b> = 25.4 s	soldered on a copper heat sink with with 25.4 mm $\varnothing$
<b>x</b> = 25.0 w	soldered on copper heat sink with with 25.0 mm $\varnothing$
<b>x</b> = FC	mounted on a 1 m single mode fiber cable with FC connector

#### Low intensity spectral reflectance

